

Reg No.: _____

Name: _____

APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY
FIRST SEMESTER B.TECH DEGREE EXAMINATION(S), MAY 2019

Course Code: BE101-04

Course Name: INTRODUCTION TO ELECTRONICS ENGINEERING

Max. Marks: 100

Duration: 3 Hours

PART A

Answer all questions, each carries 5 marks.

Marks

- 1 Explain the colour coding for resistors. Indicate the colour code for a $33\text{K}\Omega$, 2% tolerance resistor. (5)
- 2 A Germanium diode carries a current of 1 mA at 20°C when a forward bias of 0.15 V is applied. Estimate the reverse saturation current for that diode. Also, calculate the forward bias voltage required to produce a diode current of 20 mA at the same temperature. (5)
- 3 What do you mean by Q-point? What are the factors affecting the stability of Q-point? (5)
- 4 List the major difference between JFET and BJT. (5)
- 5 Draw and explain a voltage doubler circuit (5)
- 6 Explain the working of a zener diode regulator. (5)
- 7 Explain with block diagram the operation of analog multimeter. (5)
- 8 Explain the terms accuracy, precision, sensitivity related to electronic measuring instruments. (5)

PART B

Answer six questions, one full question from each module and carries 10 marks.

Module I

- 9 Explain the constructional details and features of a carbon film resistor and a wire wound resistor with the help of neat diagrams. (10)

OR

- 10 a) Explain the working principle of electro mechanical relay with diagram. (7)
- b) Explain the working principle of transformers with diagram. (3)

Module II

- 11 Explain the V-I characteristics of a Germanium diode at room temperature. Draw the V-I characteristics of the same diode at a higher temperature and explain the effect of temperature on the graph. (10)

OR

- 12 a) Explain the working principle of LEDs? Also discuss the various types of LEDs. (6)
b) Explain about the working of a photo diode. (4)

Module III

- 13 Explain the input and output characteristics of an NPN transistor in CE configuration. Indicate active, cut-off and saturation regions in output characteristics. (10)

OR

- 14 Explain an RC coupled amplifier with the frequency response. (10)

Module IV

- 15 a) Explain the structure and operation of n-channel FET. (6)
b) Draw and explain the drain and transfer characteristic curves of n-channel FET (4)

OR

- 16 a) Explain the working principle of SCR. Draw and explain the characteristics of SCR. (8)
b) Explain holding current and latching currents in SCR. (2)

Module V

- 17 a) Explain the working of half wave rectifier with diagram (4)
b) Derive the RMS value, DC value, ripple factor of a Half Wave Rectifier. (6)

OR

- 18 Explain the working of SMPS with block diagram. What are its applications? (10)

Module VI

- 19 Describe the working of CRT with diagram. (10)

OR

- 20 a) Draw the block diagram of a digital storage oscilloscope and explain its working. (8)
b) Give the advantages of DSO over CRO (2)
